NSN 5961-01-026-1565

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Inclosure Material:	
Metal	
Overall Length:	
0.250 inches	
Terminal Length:	
0.500 inches	
Overall Diameter:	
Between 0.315 inches and 0.335 inches	
Internal Configuration:	
Junction contact	
Joint Electronic Device Engineering Council/jedec/case Outline Designation:	
То-39	
Electrode Internally-electrically Connected To Case:	
Collector	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
0.020 inches	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
36.0 breakdown voltage, collector-to-base, emitter open and 18.0 breakdown voltage, col	llector-to-emitter, base open and 4.0 breakdown
voltage, emitter-to-base, collector open	
Current Rating Per Characteristic:	
500.00 milliamperes source cutoff current	
Power Rating Per Characteristic:	
7.0 watts small-signal input power, common-collector absolute	
Maximum Operating Tempurature Per Measurement Point:	
200.0 degrees celsius ambient air	
Special Features:	
Junction pattern arrangement: npn	
Terminal Type And Quantity:	
3 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	
Filg:	